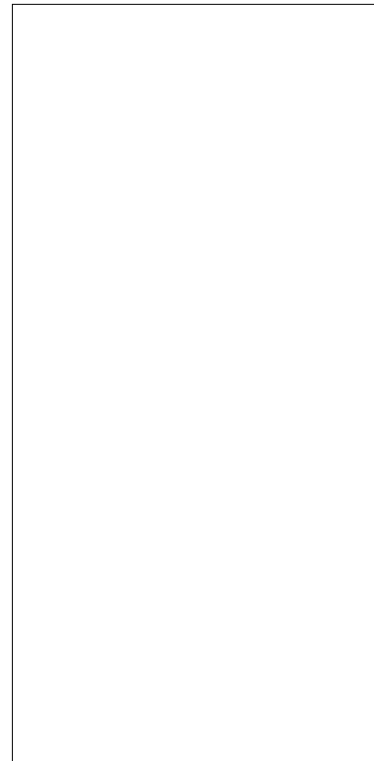


JCT816AH 16A SCR

Rev.A.1.1

**DESCRIPTION:**

With high ability to withstand the shock loading of large current, JCT816AH of silicon controlled rectifiers provides high  $dV/dt$  rate with strong resistance to electromagnetic interference. It is especially recommended for use on solid state relay, motorcycle, power charger, T-tools etc. From all three terminals to external heatsink, JCT816AH provides a rated insulation voltage of 2500  $V_{RMS}$ , complying with UL standards (File ref: E252906). Package TO-220A is RoHS compliant.



**MAIN FEATURES**

Symbol	Value	Unit
$I_{T(RMS)}$	16	A
$V_{DRM}/V_{RRM}$	800	V
$I_{GT}$	"15	mA

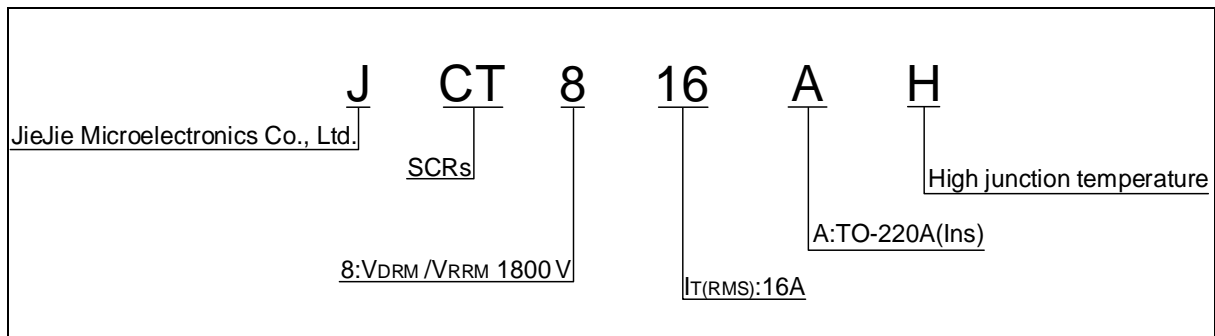
**ABSOLUTE MAXIMUM RATINGS**

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-150	
Operating junction temperature range	$T_j$	-40-150	
Repetitive peak off-state voltage ( $T_j=25^\circ C$ )	$V_{DRM}$	800	V
Repetitive peak reverse voltage ( $T_j=25^\circ C$ )	$V_{RRM}$	800	V
Average on-state current ( $T_c 0 118^\circ C$ )	$I_{T(AV)}$	10	A
RMS on-state current ( $T_c 0 118^\circ C$ )	$I_{T(RMS)}$	16	A
Non repetitive surge peak on-state current ( $t_p=10ms, T_j=25^\circ C$ )	$I_{TSM}$	150	A
Non repetitive surge peak on-state current ( $t_p=8.3ms, T_j=25^\circ C$ )		165	
$I^2t$ value for fusing ( $t_p=10ms, T_j=25^\circ C$ )	$I^2t$	113	$A^2s$
Critical rate of rise of on-state current ( $I_G=2 \times I_{GT}, f=100Hz, T_j=150^\circ C$ )	$di/dt$	150	A/s
Peak gate current ( $t_p=20 \mu s, T_j=150^\circ C$ )	$I_{GM}$	5	A

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Average gate power dissipation ( $T_j=150$ )	$P_{G(AV)}$	1	W
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ORDERING INFORMATION



MARKING

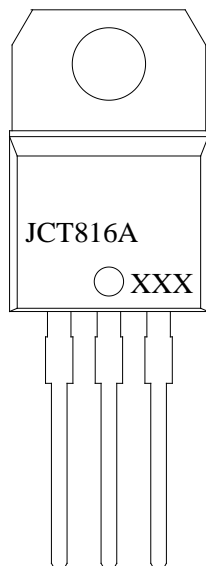


FIG.1: Maximum power dissipation versus RMS on-state current

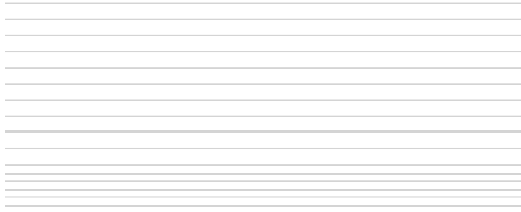
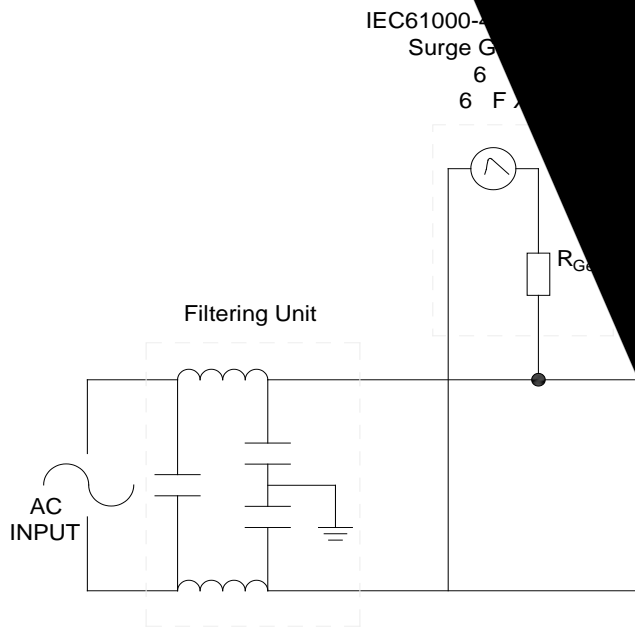


FIG.2: RMS on-state current versus case temperature

# JCT816AH

FIG.7 ÖTest circuit for inductive and



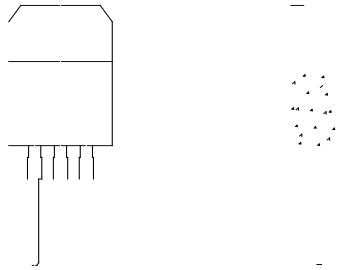
## ORDERING INFORMATION

Order code	Voltage $V_{DRM}/V_{RRM}$ (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
JCT816AH	800	15	TO-220A(Ins)	50	Tube

## Document Revision History

Date	Revision	Changes
Jun.15, 2023	A.1.0	Last update
Oct.11, 2025	A.1.1	Revise PACKAGE MECHANICAL DATA

PACKAGE MECHANICAL DATA



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